## NSN 5961-01-231-3938

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-231-3938 **Inclosure Material:** Metal **Overall Length:** 1.252 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.313 inches Voltage Rating In Volts Per Characteristic: 200.0 working peak reverse voltage and 250.0 nonrepetitive peak reverse voltage and 140.0 reverse voltage, total rms **Current Rating Per Characteristic:** 12.00 amperes collector current, dc absolute **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Yes - demil/mli

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